Correction

Correction: Deng, F., *et al.* A CMOS Humidity Sensor for Passive RFID Sensing Applications. *Sensors* 2014, *14*, 8728–8739

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The authors wish to make the following corrections to this paper [1]. Figures 2, 3 and 4b were adapted from reference [2]. The corrected Figure 7 should be,

Figure 7. Measured outputs for different ΔC_{sensor} of the sensor with 2 μm-thick polyimide layer at 25 °C.
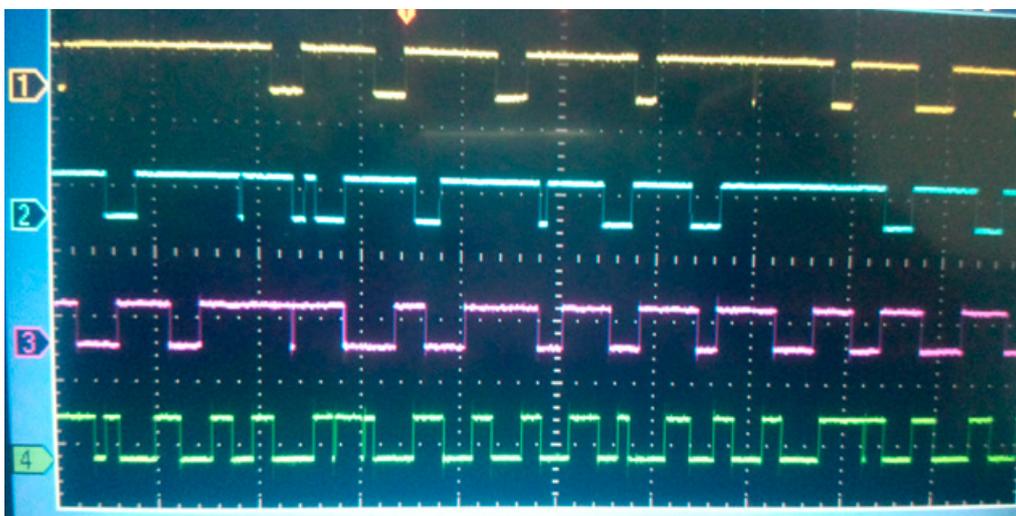
The authors would like to apologize for any inconvenience caused to the readers by these changes.

References

1. Deng, F.; He, Y.; Zhang, C.; Feng, W. A CMOS Humidity Sensor for Passive RFID Sensing Applications. *Sensors* **2014**, *14*, 8728–8739.
2. Shulaker, M.M.; Rethy, J.V.; Hills, G.; Wei, H.; Chen, H.Y.; Gielen, G.; Wong, H.S.P.; Mitra, S. Sensor-to-digital interface built entirely with carbon nanotube FETs. *IEEE J. Solid State Circuits* **2014**, *49*, 190–201.